2SC2636

Silicon NPN epitaxial planar type

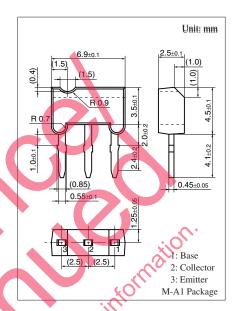
For high-frequency amplification/oscillation

■ Features

- High transition frequency f_T
- M type package allowing easy automatic and manual insertion as well as stand-alone fixing to the printed circuit board

■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Unit	
Collector-base voltage (Emitter open)	V _{CBO}	30	V
Collector-emitter voltage (Base open)	V _{CEO}	20	V
Emitter-base voltage (Collector open)	V_{EBO}	3	V
Collector current	I_C	50	mA
Collector power dissipation	P _C	400	mW
Junction temperature	Tj	150	°C
Storage temperature	T _{stg}	-55 to +150	°C



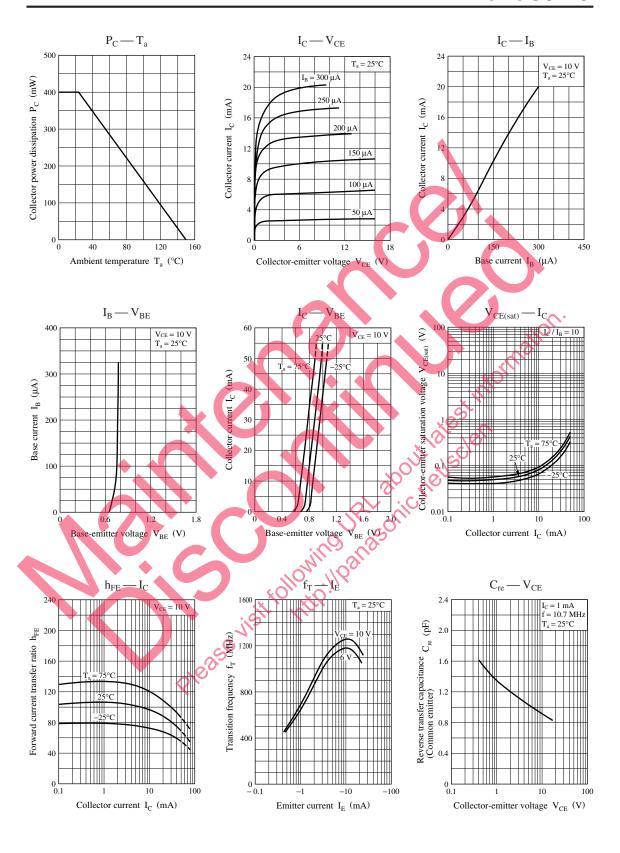
■ Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	V_{CBO}	$I_{\rm C} = 100 \mu \text{A}, I_{\rm E} = 0$	30			V
Emitter-base voltage (Collector open)	$V_{ m EBO}$	$I_{\rm E} = 10 \mu \text{A} I_{\rm C} = 0$	3			V
Base-emitter voltage	V_{BE}	$V_{CB} = 10 \text{ V}, I_{E} = -2 \text{ mA}$		720		mV
Forward current transfer ratio *	h _{FE}	V _{CE} 10 V, Q = 2 mA	25			_
Transition frequency	f _T	$V_{CB} = 10 \text{ V}, I_E = -15 \text{ mA}, f = 200 \text{ MHz}$	600	1 200	1600	MHz
Power gain	G _P	$V_{CB} = 10 \text{ V}, I_E = -1 \text{ mA}, f = 100 \text{ MHz}$		20		dB
Reverse transfer capacitance	cerb	$V_{CB} = 6 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$		0.8		pF
(Common base)	0					
Reverse transfer capacitance	C _{re}	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}, f = 10.7 \text{ MHz}$			1.5	pF
(Common emitter)						
Collector-base parameter	r _{bb} ' • C _C	$V_{CB} = 10 \text{ V}, I_{E} = -10 \text{ mA}, f = 31.9 \text{ MHz}$			25	ps

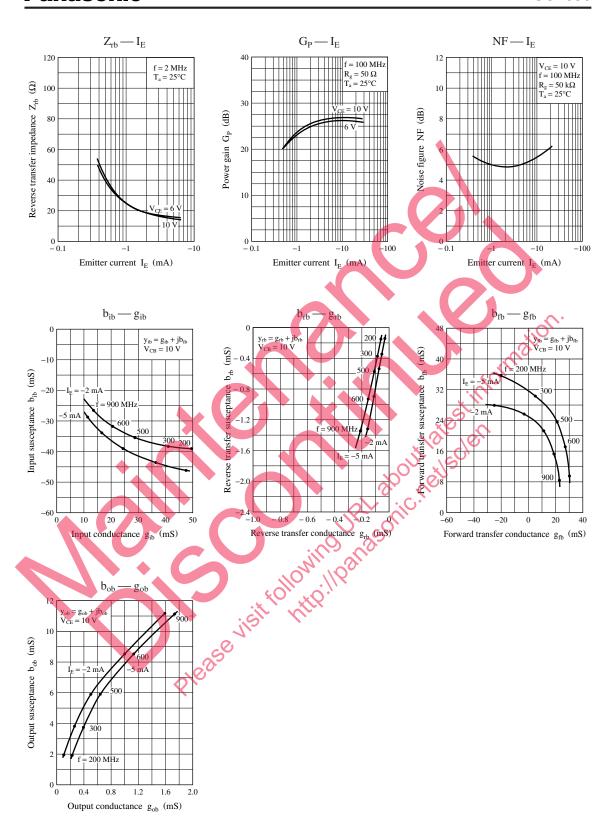
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. *: Rank classification

Rank	Т	S
h_{FE}	600 to 1 300	900 to 1 600



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